# PWR-SMP220 **PWM Power Supply IC 85-265 VAC Input** Isolated, Regulated DC Output



# **Product Highlights**

## Integrated Power Switch and CMOS Controller

- Output power up to 20 W from rectified 220 VAC input, 12 W from rectified universal (85 to 265 VAC) input
- External transformer provides isolated output voltages
- Configurable for transformer winding or optocoupler feedback

## High-voltage, Low-capacitance MOSFET Output

- Designed for 120/220 V off-line applications
- Can also be used with DC inputs from 36 V to 400 V
- · Low capacitance allows for high frequency operation

### High-speed Voltage-mode PWM Controller

- Internal pre-regulator self-powers the IC on start-up
- Wide V<sub>RIAS</sub> voltage range
- · Optimized for optocoupler feedback

### **Built-In Self-protection Circuits**

- Cvcle-bv-cvcle current limit
- Output overvoltage protection
- Shutdown/auto-restart cycling
- Input undervoltage lockout
- Thermal shutdown

# Description

The PWR-SMP220, intended for 220 V or universal off-line isolated power supply applications, combines a high voltage power MOSFET switch with a switchmode power system controller in a monolithic integrated circuit. Few external components are required to implement a small, low-cost, isolated, off-line power supply.

The PWR-SMP220 has been designed for maximum flexibility in feedback techniques. An error amplifier has been included for use with feedback winding regulation, or it can be bypassed for direct optical feedback to the PWM comparator.

The controller section of the PWR-SMP220 contains all the blocks required to drive and control the power stage: off-line pre-regulator, oscillator, bandgap reference, error amplifier, gate driver, and circuit protection. This voltage-mode Pulse Width Modulation control circuit is optimized for flyback topologies, but may be used with other topologies as well.

The PWR-SMP220 is available in a 20-pin batwing SOIC package.

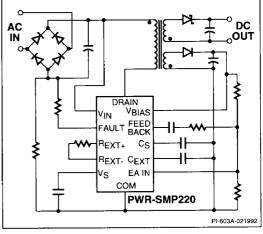


Figure 1. Typical Application

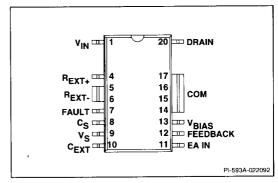


Figure 2. Pin Configuration

ORDERI	NG INFORMATI	ON
PART NUMBER	PACKAGE	TEMP RANGE
PWR-SMP220SRI	20-pin PWR SOIC	-40 to 85°C



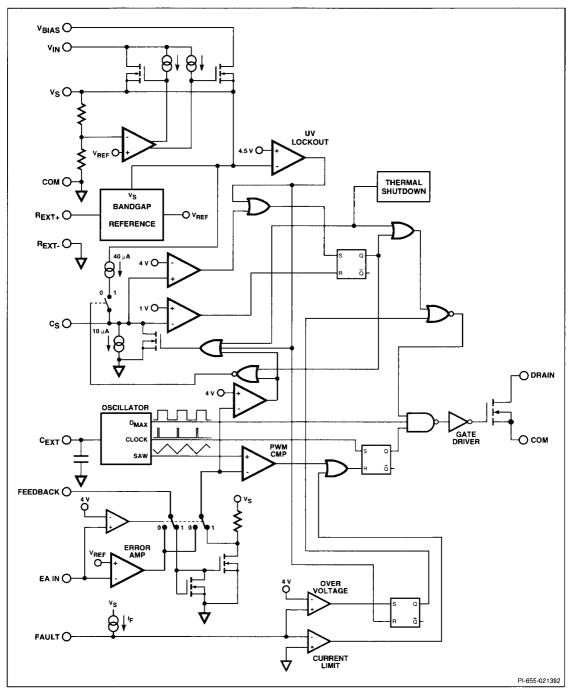


Figure 3. Functional Block Diagram of the PWR-SMP220.

## **Pin Functional Description**

#### Pin 1:

High voltage  $V_{\rm IN}$  for connection to the high voltage pre-regulator used to self-power the device during start-up.

#### Pin 4:

A resistor placed between  $\mathbf{R}_{\text{EXT+}}$  and  $\mathbf{R}_{\text{EXT+}}$  sets the internal bias currents.

#### Pin 5, 6:

 $\mathbf{R}_{\text{EXT-}}$  is the return for the reference current. Do not connect to ground plane.

#### Pin 7:

The **FAULT** pin is used with an external resistor to provide protection of the output during overcurrent and overvoltage conditions.

#### Pin 8:

 $C_s$  is used to set the shutdown/autorestart cycle time.

#### Pin 9:

Connection for a bypass capacitor for the internally generated  $V_s$  supply.

#### Pin 10:

C<sub>EXT</sub> is used to set the oscillator frequency. Adding external capacitance lowers the PWM frequency.

#### Pin 11:

**EA IN** is the error amplifier inverting input for connection to the external feedback and compensation networks. Connecting this pin to  $V_s$  disables the error amplifier when using optocoupler feedback.

#### Pin 12:

**FEEDBACK** can be driven directly by an optocoupler output, bypassing the internal error amplifier. When using transformer winding feedback control, this pin is used as the error amplifier output for connection to the external compensation network.

#### Pin 13:

**V**<sub>BIAS</sub> is the bootstrap voltage used to self-power the device once the supply is operating.

#### Pin 14, 15, 16, 17:

**COM** connections. Ground or reference point for the circuit.

#### Pin 20:

Open DRAIN of the output MOSFET.

## **PWR-SMP220 Functional Description**

#### **Bias Regulator**

The onboard supply voltage  $(V_s)$  is supplied from either of two high-voltage linear regulators. The V<sub>IN</sub> linear regulator draws current from the high-voltage bus while the V<sub>BIAS</sub> regulator draws current from a voltage generated from a transformer winding. The V<sub>IN</sub> regulator dissipates significant power levels and should be cut off during normal operation for improved efficiency. The V<sub>s</sub> error amplifier has a built-in preference for generating  $V_s$  from the  $V_{BIAS}$  regulator, which automatically cuts off the  $V_{\text{\tiny IN}}$ regulator during normal operation. During start-up and under power supply fault conditions, the bias error amplifier generates  $V_s$  from the  $V_{in}$  regulator.

 $V_s$  is the supply voltage for the controller and driver circuitry. An external bypass capacitor connected to  $V_s$  is required for filtering and noise immunity. The value of  $V_s$  also determines when the internal undervoltage lockout is enabled. Undervoltage lockout disables the power MOSFET until  $V_s$  is within its normal operating range.

## **Bandgap Reference**

 $V_{REF}$  is a 1.25 V reference voltage generated by the temperature compensated bandgap reference. This reference voltage is used for setting thresholds for comparators, amplifiers, and the thermal shutdown circuit. The external resistor connected between  $R_{EXT+}$  and  $R_{EXT-}$  and the bandgap reference set the proper internal bias current levels for the various internal circuits.

#### Oscillator

The oscillator linearly charges and discharges the combined internal and external capacitance between two different voltage levels to create a sawtooth waveform for the pulse width modulator. Two digital signals, D<sub>MAX</sub> and CLOCK are also generated. D<sub>MAX</sub> corresponds to the rising portion of the sawtooth waveform, and is used to gate the MOSFET driver. A short CLOCK pulse is used to reset the current limit comparator at the beginning of each cycle. The maximum duty cycle is equal to the ratio of the charge time to the total period of the oscillator waveform.

## **PWR-SMP220 Functional Description (cont.)**

### **Optional Error Amplifier Circuitry**

The control loop circuitry is configurable for either secondary-referenced optocoupler control or primary-referenced feedback winding control. In both cases, a control voltage is generated and sent to the pulse width modulator for conversion to a duty cycle.

Connecting the EA IN input to V<sub>s</sub> configures the control loop for connection to an external optocoupler. In this mode the internal error amplifier is disabled. The optocoupler output transistor emitter connects directly to FEEDBACK, which is configured as an N-channel MOSFET transistor "diode". This connection presents a low impedance and wide collector-emitter voltage to the optocoupler transistor for improved frequency response and speed. The diode current is converted to the control voltage by a mirror transistor and resistor.

For primary-referenced feedback winding control, the EA IN input is simply connected through a resistor divider to the feedback voltage. The internal error amplifier is automatically configured and connected to the pulse width modulator. EA IN is the inverting input to the error amplifier. The non inverting input is internally connected to the 1.25 V bandgap reference. FEEDBACK is connected to an external feedback compensation network for tailoring the frequency response for proper bandwidth, gain margins, and phase margins.

#### Pulse Width Modulator

The pulse width modulator implements a voltage mode control loop by driving the power MOSFET with a duty cycle proportional to a control voltage. The duty cycle signal is generated by a comparator which compares the control voltage with a sawtooth waveform. A clock signal from the oscillator sets a latch which turns on the power MOSFET. The pulse width modulator resets the latch turning off the power MOSFET. The D<sub>MAX</sub> signal from the oscillator limits the maximum duty cycle by gating the driver.

#### **Fault Protection**

The FAULT pin is used to implement both cycle-by-cycle MOSFET transistor current limiting and latching output overvoltage protection.

The FAULT pin latches off the power switch when an overcurrent condition causes the voltage on this pin to drop to zero. The DRAIN current is sensed by an external resistor. An internal current source biases the FAULT signal during normal operation. During an overcurrent condition, current flows in the current sense resistor, causing the voltage on the FAULT pin to decrease. If the voltage on the FAULT pin falls below COM for longer than the delay time, the power switch will be latched off until the beginning of the next clock cycle. If this condition persists, the output voltage will fall out of regulation, triggering a shutdown/auto-restart cycle.

For latching overvoltage protection, an external optocoupler can be used to drive the FAULT pin above the 4 V threshold of the overvoltage comparator. This comparator sets a latch that will turn off the power MOSFET until the latch is reset by removing and restoring input power.

#### Shutdown/Auto-restart

The PWR-SMP220 contains an autorestart function which will shut off the power supply if the output voltage falls out of regulation. The PWR-SMP220 will try to restart and will test the output after a delay. The PWR-SMP220 will remain shut off for the amount of time determined by the value of C<sub>s</sub>, and will then begin the auto-restart cycle. The power supply will resume normal operation if the fault condition has been removed. The power supply will continuously cycle if the output is not regulated within the turn-on delay as determined by C<sub>s</sub>. During normal operation, Cs is quickly discharged to 0 V. This function can be disabled by connecting the C<sub>s</sub> pin to COM.

#### Overtemperature Protection

Temperature protection is provided by a precision analog circuit that turns the power switch off and reduces supply current when the switch junction gets too hot (typically 140°C). When the circuit has cooled past the hysterisis temperature, normal operation resumes.



# 12 W Universal Off-line Power Supply with Optocoupler Feedback

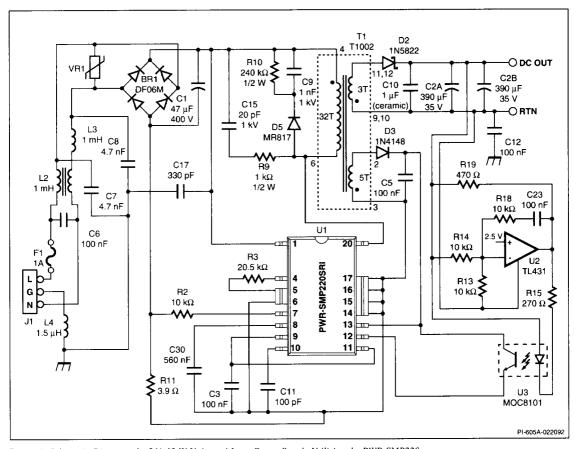


Figure 4. Schematic Diagram of a 5 V, 12 W Universal Input Power Supply Utilizing the PWR-SMP220.

# **General Circuit Operation**

The flyback power supply circuit shown in Figure 4, when operated with the T1002 standard transformer (see DA-3), will produce a 5 volt, 12 watt power supply that will operate from 85 to 265 V(rms) AC input voltage. The output voltage is directly sensed and accurately regulated by a secondary-referenced error amplifier. The error amplifier drives an error signal through an optocoupler to the PWR-SMP220, which directly controls the duty cycle of the integrated high voltage MOSFET switch.

The effective output voltage can be finetuned by adjusting the resistive divider formed by R13 and R14. Other output voltages are possible by adjusting the transformer turns ratios as well as the resistor divider.

AC power is rectified and filtered by BR1 and C1 to create the high voltage DC bus applied to the primary winding of transformer T1. The other side of the transformer primary is driven by the integrated high voltage MOSFET

transistor within the PWR-SMP220. The clamp circuit implemented by R10, C9, and D5 clamps the leading edge voltage spike caused by transformer leakage inductance to a safe value. Ringing caused by parasitic capacitance and leakage inductance is damped by C15 and R9. The power secondary winding is rectified and filtered by D2, C2A, C2B, and C10 to create the desired output voltage. The bias winding is rectified and filtered by D3 and C5 to create a bias voltage to the PWR-SMP220, which



## **General Circuit Operation (cont.)**

effectively cuts off the high voltage internal linear regulator. Common mode emission currents which flow between the primary windings of the transformer and the secondary output circuitry are attenuated by C12, C17, C7, C8, and L2. Differential mode emission currents caused by pulsating currents at the input of the power supply are attenuated by C6 and L3. Voltage spikes on the AC line are clamped by VR1.

Internal bias currents are accurately set by R3. Bypass capacitor C3 filters current spikes on the internally generated voltage source V<sub>s</sub>. The oscillator frequency is determined by C11. Transistor switch current is sensed by resistor R11. The initial voltage level at the fault pin is determined by resistor R2. C30 determines the auto-restart time interval.

The secondary-referenced error amplifier control system is implemented with the TL431 shunt regulator (U2). This device consists of an accurate 2.5 V bandgap reference, error amplifier, and driver. The output voltage is sensed, divided by R13 and R14, and applied to the inverting input of the error amplifier. The non-inverting input of the error amplifier is internally connected to the bandgap reference voltage. The frequency response of the error amplifier is determined by the compensation network consisting of R18, C23, and the high frequency gain setting resistor R14. Bias current of 2 mA minimum for U2 is provided by resistor R19. The LED current in the optocoupler is limited by resistor R15. Optocoupler U3 drives the error signal into the FEEDBACK pin of the PWR-SMP220. Note that the EA IN pin must be connected to the V<sub>c</sub> pin to properly configure the PWR-SMP220 for this type of control.

To reduce device power dissipation and temperature rise during normal operation, the voltage applied to VBIAS must be greater than the minimum specified value to ensure complete cutoff of the high voltage linear regulator. Ensure that the maximum specified voltage on the V<sub>BIAS</sub> pin is not exceeded when adjusting the value of the output voltage.

# **Implementing Output Overvoltage Protection**

If the load is extremely sensitive to overvoltage conditions, an overvoltage shutdown function can be implemented as shown in Figure 5. The output voltage is fed back to the PWR-SMP220 via an

op amp and optocoupler. If the voltage at pin 7 is greater than 4 V, the internal latch will shut off the output.

The PWR-SMP220 must be restarted by removing the input voltage and then reapplying it, causing the latch to reset and the circuit to begin a new startup cycle.

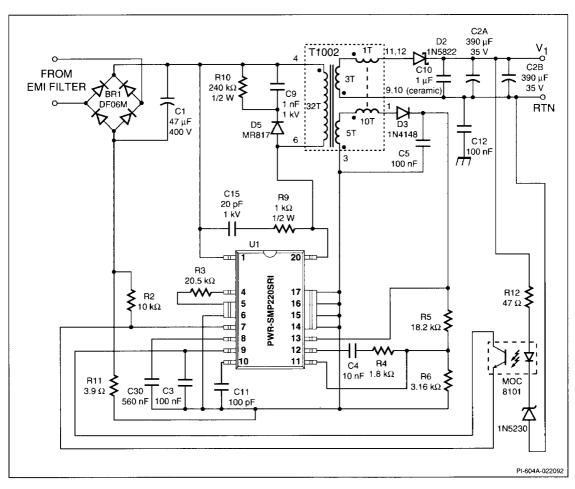


Figure 5. Implementing Feedback Winding Regulation and Output Overvoltage Protection.

# **PRELIMINARY**

ABSOLUTE MAXIMUM RATINGS'						
Drain Voltage700 V	Power Dissipation (T <sub>A</sub> = 25°C)					
V <sub>IN</sub> Voltage500 V	$(T_A = 70^{\circ}C)$					
V Voltage	Thermal Impedance ( $\hat{\theta}_{IA}$ )30°C/W					
Drain Current <sup>(2)</sup> 1.3 A	Thermal Impedance $(\theta_{IC})^{(6)}$					
Input Voltage <sup>(3)</sup> 0.3 V to $V_s + 0.3 V$	•					
Storage Temperature65 to 125°C	1. Unless noted, all voltages referenced to COM, $T_A = 25^{\circ}\text{C}$					
Ambient Temperature40 to 85°C	2. 300 μs, 2% duty cycle.					
Junction Temperature <sup>(4)</sup> 150°C	3. Does not apply to V <sub>IN</sub> or DRAIN.					
Lead Temperature <sup>(5)</sup>	4. Normally limited by internal circuitry.					
· ·	5. 1/16" from case for 5 seconds.					
	6. Measured at pin 15/16.					

Specification Sy	Symbol	Test Conditions, Unless Otherwise Specified: $V_{IN} = 325 \text{ V}, V_{BIAS} = 8.5 \text{ V}, COM = 0 \text{ V}$ $R_{EXT} = 20.5 \text{ k}\Omega, C_{S} = 560 \text{ nF}$	Test Limits			Units	
		$T_A = -40 \text{ to } 85^{\circ}\text{C (See Note 1)}$	MIN	TYP	MAX		
OSCILLATOR							
Output Frequency	f <sub>osc</sub>	C <sub>EXT</sub> = Open	650	750	850	kHz	
PULSE WIDTH MODULATOR							
Duty Cycle	DC	C <sub>EXT</sub> = Open	0-35	0-40		%	
Range	DC	f <sub>osc</sub> = 200 kHz	0-48	0-50		/6	
Optocoupler Output Current	I <sub>c</sub>	EA IN = V <sub>s</sub> , Maximum Duty Cycle	400		600	μΑ	
Dynamic Control Current	i <sub>c</sub>	0 to Maximum Duty Cycle	50	100	200	μΑ	
CIRCUIT PROTE	CTION						
FAULT Offset Current				100		μΑ	
FAULT OV Threshold	V <sub>ov</sub>			4		٧	
FAULT Current Limit Threshold	V <sub>ILIMIT</sub>			0		V	

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Specification	<b>Symbol</b> $V_{IN} = 325 \text{ V}, V_{BIAS} = 8.5 \text{ V}, COM = 0$	Unless Otherwise Specified: $V_{IN} = 325 \text{ V}, V_{BIAS} = 8.5 \text{ V}, \text{COM} = 0 \text{ V}$ $R_{EXT} = 20.5 \text{ k}\Omega, C_{S} = 560 \text{ nF}$	Test Limits			Units
		$T_A = -40 \text{ to } 85^{\circ}\text{C}$ (See Note 1)	MIN	TYP	MAX	
CIRCUIT PROTEC	CTION (co	nt.)				
Current Limit Delay Time	t <sub>d(off)</sub>	See Figure 6	75	150	250	ns
Thermal Shutdown Temperature			125	140		°C
Thermal Shutdown Hysteresis				15		°C
SHUTDOWN/AUT	O-RESTA	RT				
ON Time	t <sub>on</sub>	See Figure 7		38		ms
OFF Time	t <sub>off</sub>	See Figure 7		150		ms
Reset Time	t <sub>RESET</sub>	See Figure 7		12.5		ms
Charge/Discharge Ratio				4:1		
Upper Threshold Voltage	$\mathbf{V}_{_{THU}}$			4.0		<b>&gt;</b>
Lower Threshold Voltage	V <sub>THL</sub>			1.0		<b>V</b>
ERROR AMPLIFI	ER					
Reference Voltage	$V_{_{REF}}$		1.21	1.25	1.29	٧
Reference Voltage Temperature Drift	$\Delta V_{REF}$			50		ppm/°C
Gain-Bandwidth Product				500		kHz
DC Gain	A <sub>vol</sub>		60	80		dB
Output Impedance	<b>Z</b> out			1.5		kΩ

# **PRELIMINARY**

Specification	Symbol	Test Conditions, Unless Otherwise Specified: $V_{IN} = 325 \text{ V}, V_{BIAS} = 8.5 \text{ V}, COM = 0 \text{ V}$ $R_{EXT} = 20.5 \text{ k}\Omega, C_S = 560 \text{ nF}$ $T_A = -40 \text{ to } 85^{\circ}\text{C} \text{ (See Note 1)}$		Test Limits			Units
				MIN	TYP	MAX	
OUTPUT (cont.)							
ON-State Resistance	R <sub>DS(ON)</sub>	I <sub>D</sub> = 200 mA	$T_{j} = 25^{\circ}C$ $T_{j} = 115^{\circ}C$			7.2 13	Ω
ON-State Current	I <sub>D(ON)</sub>	V <sub>DS</sub> = 10 V	$T_{j} = 25^{\circ}C$ $T_{j} = 115^{\circ}C$	0.7	1.0 0.7		Α
OFF-State Current	I <sub>DSS</sub>	V <sub>DRAIN</sub> = 560 V, T <sub>A</sub> = 115°C			10	50	μА
Breakdown Voltage	BV <sub>DSS</sub>	I <sub>DRAIN</sub> = 100 μA, T <sub>A</sub> = 25°C		700			٧
Output Capacitance	C <sub>oss</sub>	V <sub>DRAIN</sub> = 25 V, f = 1 MHz			150		pF
Output Stored Energy	E <sub>oss</sub>	V <sub>DRAIN</sub> = 400 V			2000		nJ
Rise Time	t,	See Figure 6			70	150	ns
Fall Time	t <sub>f</sub>	See Figure 6			70	150	ns
SUPPLY							
Pre-regulator Voltage	V <sub>IN</sub>			36		500	٧
Off-line Supply Current	I <sub>IN</sub>	V <sub>BIAS</sub> not connected, C <sub>EXT</sub> = Open V <sub>BIAS</sub> > 8.25 V Thermal Shutdown ON			3	4.5 0.1 2	mA
V <sub>BIAS</sub> Supply Voltage	V <sub>BIAS</sub>	V <sub>BIAS</sub> externally supplied		8.25		30	٧
V <sub>BIAS</sub> Supply Current	BIAS	V <sub>BIAS</sub> externally supplied			3	4.5	mA
V <sub>s</sub> Source Voltage	V <sub>s</sub>			5.1		6.0	٧
V <sub>s</sub> Source Current	Is					400	μΑ

## NOTES:

 Applying >3.5 V to the C<sub>EXT</sub> pin activates an internal test circuit that turns on the output switch continuously. Destruction of the part can occur if the output of the PWR-SMP220 is connected to a high voltage power source when the test circuit is activated.

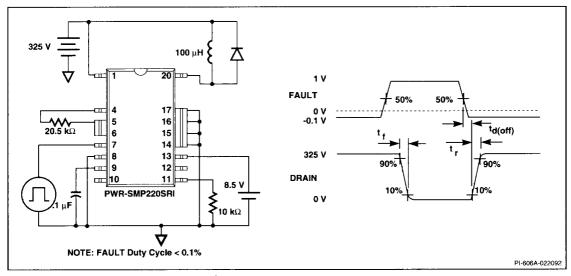


Figure 6. Current Limit Delay/Switching Time Test Circuit.

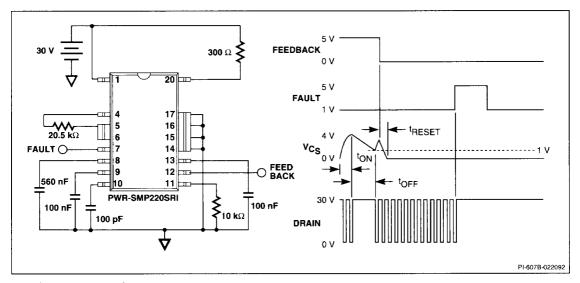
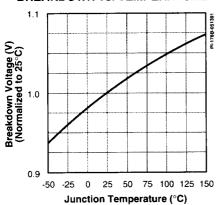


Figure 7. Auto-restart Test Circuit.

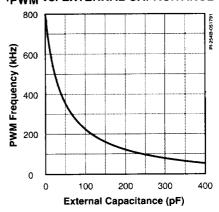


# **PRELIMINARY**

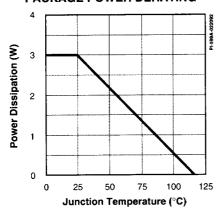
### **BREAKDOWN vs. TEMPERATURE**



# **fpwm** vs. EXTERNAL CAPACITANCE



## **PACKAGE POWER DERATING**



## TRANSIENT THERMAL IMPEDANCE

